

Notice of Allowability

Application No.

10/787,331

Examiner

Ly D Pham

Applicant(s)

LESEA, AUSTIN H.

Art Unit

2818

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address--

All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. **THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS.** This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308.

1. ☒ This communication is responsive to 24 June 2004.
2. ☒ The allowed claim(s) is/are 1-4.
3. ☒ The drawings filed on 26 February 2004 are accepted by the Examiner.
4. ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some* c) ☐ None of the:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)).

* Certified copies not received: _____.

Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application.
THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.

5. ☐ A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.
6. ☐ CORRECTED DRAWINGS (as "replacement sheets") must be submitted.
- (a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached
- 1) ☐ hereto or 2) ☐ to Paper No./Mail Date _____.
- (b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date _____.
- Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).
7. ☐ DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.

Attachment(s)

1. ☒ Notice of References Cited (PTO-892)
2. ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
3. ☒ Information Disclosure Statements (PTO-1449 or PTO/SB/08), Paper No./Mail Date 022604
4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material
5. ☐ Notice of Informal Patent Application (PTO-152)
6. ☐ Interview Summary (PTO-413), Paper No./Mail Date _____.
7. ☐ Examiner's Amendment/Comment
8. ☒ Examiner's Statement of Reasons for Allowance
9. ☐ Other _____.


David Nelms

Supervisory Patent Examiner
Technology Center 2800

DETAILED ACTION

1. Applicant's Information Disclosure Statement, IDS, filed February 26, 2004 has been considered by the Examiner.

Response to Arguments

2. Applicant's arguments, see Remarks, filed June 24, 2004, with respect to claims 1 – 4 have been fully considered and are persuasive. The rejection of claims 1 – 4 has been withdrawn.

Allowable Subject Matter

3. Claims 1 – 4 are allowed.

4. The following is an examiner's statement of reasons for allowance:

The prior arts teach a memory cell formed of complementary NMOS and PMOS transistors, comprising:

a first inverter including first NMOS and PMOS and having first input node at the gates of the complementary transistors and first output node at the common drain;

a second inverter including second NMOS and PMOS and having second input node ... and second output node ...;

However, the prior arts fail to teach the memory cell, further comprising:

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a third NMOS and a third PMOS transistors; a fourth NMOS and fourth PMOS transistors;

the third PMOS and the fourth PMOS commonly coupled to receive a second gate bias voltage;

the third NMOS having source and drain coupled between a gate of the first NMOS and the second output node;

the fourth NMOS having source and drain coupled between a gate of the second NMOS and the first output node;

the third PMOS having source and drain coupled between a gate of the first PMOS and the second output node; and

the fourth PMOS having source and drain coupled between a gate of the second PMOS and the first output node.

5. Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

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7. A shortened statutory period for response to this action is set to expire 3 (three) months and 0 (zero) day from the date of this letter. Failure to respond within the period for response will cause the application to become abandoned (see MPEP 710.02(b)).

8. Any inquiry concerning this communication on earlier communications from the examiner should be directed to Ly Pham, whose telephone number is **571-272-1793**. The examiner can normally be reached on Monday – Friday from 8:30am to 5:00pm, alternate Friday off. The examiner's supervisor, David Nelms, can be reached at **571-272-1787**. The fax number for the organization where this application or proceeding is assigned is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

Ly Pham



July 15, 2004



David Nelms
Supervisory Patent Examiner
Technology Center 2800